

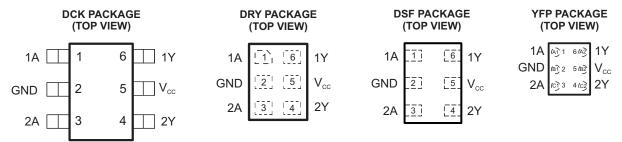
LOW-POWER DUAL INVERTER GATE

Check for Samples: SN74AUP2G04

FEATURES

- Available in the Texas Instruments NanoStar™ Package
- Low Static-Power Consumption:
 I_{CC} = 0.9 μA Max
- Low Dynamic-Power Consumption:
 C_{pd} = 4.3 pF Typ at 3.3 V
- Low Input Capacitance: C_i = 1.5 pF Typ
- Low Noise: Overshoot and Undershoot <10% of V_{CC}
- I_{off} Supports Partial-Power-Down Mode Operation
- Wide Operating V_{CC} Range of 0.8 V to 3.6 V

- Optimized for 3.3-V Operation
- 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- t_{pd} = 4.3 ns Max at 3.3 V
- Suitable for Point-to-Point Applications
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)

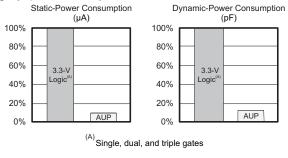


N.C. - No internal connection

See mechanical drawings for dimensions.

DESCRIPTION/ORDERING INFORMATION

The AUP family is TI's premier solution to the industry's low-power needs in battery-powered portable applications. This family ensures a very low static- and dynamic-power consumption across the entire V_{CC} range of 0.8 V to 3.6 V, resulting in increased battery life (see Figure 1). This product also maintains excellent signal integrity (see the very low undershoot and overshoot characteristics shown in Figure 2).



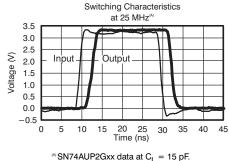


Figure 1. AUP - The Lowest-Power Family

Figure 2. Excellent Signal Integrity

The SN74AUP2G04 performs the Boolean function $Y = \overline{A}$ in positive logic.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



NanoStar[™] package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

ORDERING INFORMATION(1)

T _A	PACKAGE ⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING ⁽³⁾
	NanoStar™ - WCSP (DSBGA) 0.23-mm Large Bump - YFP (Pb-free)	Reel of 3000	SN74AUP2G04YFPR	HC_
–40°C to 85°C	QFN – DRY	Reel of 5000	SN74AUP2G04DRYR	H4
	uQFN – DSF	Reel of 5000	SN74AUP2G04DSFR	H4
	SOT (SC-70) – DCK	Reel of 3000	SN74AUP2G04DCKR	H4_

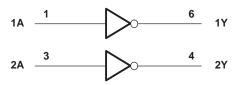
- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
- (2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.
- (3) DCK: The actual top-side marking has one additional character that designates the wafer fab/assembly site.

 YFP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the wafer fab/assembly site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, = Pb-free).

FUNCTION TABLE (Each Inverter)

INPUT A	OUTPUT Y
Н	L
L	Н

LOGIC DIAGRAM (POSITIVE LOGIC)





ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range	Supply voltage range			V
VI	Input voltage range ⁽²⁾		-0.5	4.6	V
Vo	Voltage range applied to any output in the I	nigh-impedance or power-off state ⁽²⁾	-0.5	4.6	V
Vo	Output voltage range in the high or low state (2)		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-50	mA
l _{OK}	Output clamp current	V _O < 0		-50	mA
lo	Continuous output current			±20	mA
	Continuous current through V _{CC} or GND			±50	mA
		DCK package		252	
0	Deal (3)	DRY package		234	00/14/
θ_{JA}	Package thermal impedance (3)	DSF package		300	°C/W
		YFP package		132	
T _{stg}	Storage temperature range	,	-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

⁽²⁾ The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ The package thermal impedance is calculated in accordance with JESD 51-7.



RECOMMENDED OPERATING CONDITIONS(1)

			MIN	MAX	UNIT	
V _{CC}	Supply voltage		0.8	3.6	V	
		V _{CC} = 0.8 V	V _{CC}			
.,	LPak Level County voltage	V _{CC} = 1.1 V to 1.95 V	0.65 × V _{CC}		V	
V_{IH}	High-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.6		V	
		V _{CC} = 3 V to 3.6 V	2			
		$V_{CC} = 0.8 \text{ V}$		0		
.,	Law lawal inner waltana	V _{CC} = 1.1 V to 1.95 V		0.35 × V _{CC}	V	
V_{IL}	Low-level input voltage	V _{CC} = 2.3 V to 2.7 V		0.7	V	
		V _{CC} = 3 V to 3.6 V		0.9		
V_{I}	Input voltage		0	3.6	V	
Vo	Output voltage		0	V_{CC}	V	
		V _{CC} = 0.8 V		-20	μΑ	
		V _{CC} = 1.1 V		-1.1		
	High lavel autout august	V _{CC} = 1.4 V		-1.7		
I _{OH}	High-level output current	V _{CC} = 1.65	-1.9		mA	
		$V_{CC} = 2.3 \text{ V}$		-3.1		
		$V_{CC} = 3 V$		-4		
		V _{CC} = 0.8 V		20	μΑ	
		V _{CC} = 1.1 V		1.1		
	Low-level output current	$V_{CC} = 1.4 \text{ V}$		1.7 1.9 3.1		
l _{OL}	Low-level output current	$V_{CC} = 1.65 \text{ V}$				
		$V_{CC} = 2.3 \text{ V}$				
		$V_{CC} = 3 V$	4			
Δt/Δν	Input transition rise or fall rate	V _{CC} = 0.8 V to 3.6 V		200	ns/V	
T _A	Operating free-air temperature	•	-40	85	°C	

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow of Floating CMOS Inputs, literature number SCBA004.



ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST CONDITIONS	V	T _A	= 25°C		T _A = -40°C	to 85°C	LINUT			
PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	MIN	MAX	UNIT			
	I _{OH} = -20 μA	0.8 V to 3.6 V	V _{CC} - 0.1			V _{CC} - 0.1					
	I _{OH} = -1.1 mA	1.1 V	0.75 × V _{CC}			0.7 × V _{CC}					
	I _{OH} = -1.7 mA	1.4 V	1.11			1.03					
V	I _{OH} = -1.9 mA	1.65 V	1.32			1.3		V			
V_{OH}	I _{OH} = -2.3 mA	221/	2.05			1.97		V			
	$I_{OH} = -3.1 \text{ mA}$	2.3 V	1.9			1.85					
	I _{OH} = -2.7 mA	2.1/	2.72			2.67					
	I _{OH} = -4 mA	3 V	2.6			2.55					
	I _{OL} = 20 μA	0.8 V to 3.6 V			0.1		0.1				
	I _{OL} = 1.1 mA	1.1 V		0.3	× V _{CC}		0.3 × V _{CC}				
	I _{OL} = 1.7 mA	1.4 V			0.31		0.37				
	I _{OL} = 1.9 mA	1.65 V			0.31		0.35	V			
V_{OL}	I _{OL} = 2.3 mA	221/			0.31		0.33	V			
	I _{OL} = 3.1 mA	2.3 V			0.44		0.45				
	I _{OL} = 2.7 mA	2.1/			0.31		0.33				
	I _{OL} = 4 mA	3 V			0.44		0.45				
I _I A or B input	$V_I = GND \text{ to } 3.6 \text{ V}$	0 V to 3.6 V			0.1		0.5	μΑ			
I _{off}	V_I or $V_O = 0 V$ to 3.6 V	0 V			0.2		0.6	μΑ			
Δl _{off}	V_I or $V_O = 0$ V to 3.6 V	0 V to 0.2 V			0.2		0.6	μА			
I _{CC}	$V_I = GND \text{ or } (V_{CC} \text{ to } 3.6 \text{ V}),$ $I_O = 0$	0.8 V to 3.6 V			0.5		0.9	μА			
ΔI _{CC}	$V_1 = V_{CC} - 0.6 V^{(1)}, I_0 = 0$	3.3 V			40		50	μА			
0	V V as CND	0 V		1.5							
C _i	$V_I = V_{CC}$ or GND	3.6 V		1.5				pF			
Co	V _O = GND	0 V		3				pF			

⁽¹⁾ One input at V_{CC} – 0.6 V, other input at V_{CC} or GND.

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $C_L = 5 pF$ (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	то	V _{CC}	T,	չ = 25°C	;	$T_A = -40$ °C t	o 85°C	UNIT
PARAMETER	(INPUT)	(OUTPUT)		MIN	TYP	MAX	MIN	MAX	UNIT
			0.8 V		18				
			1.2 V ± 0.1 V	2.6	7.3	12.8	2.1	15.6	
	A or D	Y	1.5 V ± 0.1 V	1.4	5.2	8.7	0.9	10.3	
t _{pd}	A or B	Ť	1.8 V ± 0.15 V	1	4.2	6.6	0.5	8.2	ns
			2.5 V ± 0.2 V	1	3	4.4	0.5	5.5	
			3.3 V ± 0.3 V	1	2.4	3.5	0.5	4.3	

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SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $C_L = 10 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	то	V	T,	_λ = 25°C	;	T _A = -40°C	to 85°C	UNIT
PARAMETER	(INPUT)	(OUTPUT)	V _{cc}	MIN	TYP	MAX	MIN	MAX	UNII
			0.8 V		21				
			1.2 V ± 0.1 V	1.5	8.5	14.7	1	17.2	
	A or B		1.5 V ± 0.1 V	1	6.2	10	0.5	11.3	
t _{pd}	AUIB	Ť	1.8 V ± 0.15 V	1	5	7.7	0.5	9	ns
			2.5 V ± 0.2 V	1	3.6	5.2	0.5	6.1	
			3.3 V ± 0.3 V	1	2.9	4.2	0.5	4.7	

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $C_L = 15 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

DADAMETED	FROM	то	V	T,	_λ = 25°C		$T_A = -40^{\circ}C t$	o 85°C	UNIT
PARAMETER	(INPUT)	(OUTPUT)	V _{cc}	MIN	TYP	MAX	MIN	MAX	UNIT
		0.8 V		24					
			$1.2 \text{ V} \pm 0.1 \text{ V}$	3.6	9.9	16.3	3.1	19.9	
	A or B		$1.5 \text{ V} \pm 0.1 \text{ V}$	2.3	7.2	11.1	1.8	13.2	
t _{pd}	AOIB	Ť	1.8 V ± 0.15 V	1.6	5.8	8.7	1.1	10.6	ns
			$2.5 \text{ V} \pm 0.2 \text{ V}$	1	4.3	5.9	0.5	7.3	
			$3.3~\text{V} \pm 0.3~\text{V}$	1	3.4	4.8	0.5	5.9	

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $C_L = 30 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	то	V	T,	_λ = 25°C		$T_A = -40$ °C to	85°C	UNIT
PARAMETER	(INPUT)	(OUTPUT)	V _{CC}	MIN	TYP	MAX	MIN	MAX	UNIT
			0.8 V		32.8				
		1.2 V ± 0.1 V	4.9	13.1	20.9	4.4	25.5		
	A or B	Y	1.5 V ± 0.1 V	3.4	9.5	14.2	2.9	16.9	20
t _{pd}	AUID		1.8 V ± 0.15 V	2.5	7.7	11	2	13.5	ns
			$2.5 \text{ V} \pm 0.2 \text{ V}$	1.8	5.7	7.6	1.3	9.4	
			$3.3 \text{ V} \pm 0.3 \text{ V}$	1.5	4.7	6.2	1	7.5	

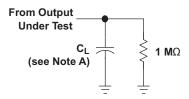
OPERATING CHARACTERISTICS

 $T_{\Delta} = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	V _{cc}	TYP	UNIT
			0.8 V	4	-
			1.2 V ± 0.1 V	4	
_	Dower discinction conscitones	f = 10 MHz	1.5 V ± 0.1 V	4	
C _{pd}	Power dissipation capacitance	I = IO WINZ	1.8 V ± 0.15 V	4	pF
			2.5 V ± 0.2 V	4.1	
			3.3 V ± 0.3 V	4.3	

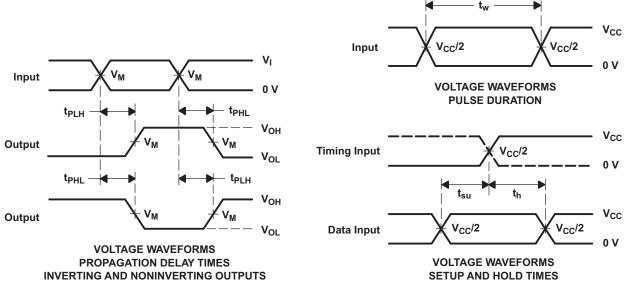


PARAMETER MEASUREMENT INFORMATION (Propagation Delays, Setup and Hold Times, and Pulse Width)



LOAD CIRCUIT

	V _{CC} = 0.8 V	V _{CC} = 1.2 V ± 0.1 V	V _{CC} = 1.5 V ± 0.1 V	V _{CC} = 1.8 V ± 0.15 V	V_{CC} = 2.5 V \pm 0.2 V	V _{CC} = 3.3 V ± 0.3 V
$egin{array}{c} \mathbf{C_L} \\ \mathbf{V_M} \\ \mathbf{V_I} \end{array}$	5, 10, 15, 30 pF V _{CC} /2 V _{CC}	5, 10, 15, 30 pF V _{CC} /2 V _{CC}	5, 10, 15, 30 pF V _{CC} /2 V _{CC}	5, 10, 15, 30 pF V _{CC} /2 V _{CC}	5, 10, 15, 30 pF V _{CC} /2 V _{CC}	5, 10, 15, 30 pF V _{CC} /2 V _{CC}

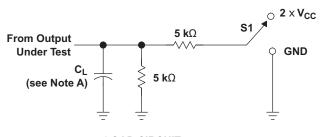


- A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50~\Omega$, for propagation delays $t_t/t_f = 3$ ns, for setup and hold times and pulse width $t_t/t_f = 1.2$ ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLH} and t_{PHL} are the same as t_{pd} .
- F. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms



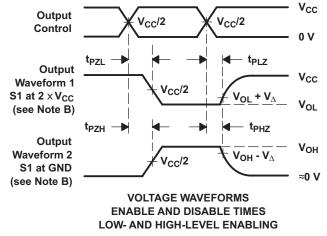
PARAMETER MEASUREMENT INFORMATION (Enable and Disable Times)



TEST	S1
t _{PLZ} /t _{PZL}	2 × V _{CC}
t _{PHZ} /t _{PZH}	GND

LOAD CIRCUIT

	V _{CC} = 0.8 V	V _{CC} = 1.2 V ± 0.1 V	V _{CC} = 1.5 V ± 0.1 V	V _{CC} = 1.8 V ± 0.15 V	V_{CC} = 2.5 V \pm 0.2 V	V _{CC} = 3.3 V ± 0.3 V
C _L	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V _M	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2
V _I	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}
V _Δ	0.1 V	0.1 V	0.1 V	0.15 V	0.15 V	0.3 V



- A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_r/t_f = 3$ ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
- F. t_{PLH} and t_{PHL} are the same as t_{pd} .
- G. All parameters and waveforms are not applicable to all devices.

Figure 4. Load Circuit and Voltage Waveforms



PACKAGE OPTION ADDENDUM



10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74AUP2G04DCKR	ACTIVE	SC70	DCK	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(H45, H4F)	Samples
SN74AUP2G04DRYR	ACTIVE	SON	DRY	6	5000	RoHS & Green	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	H4	Samples
SN74AUP2G04DSFR	ACTIVE	SON	DSF	6	5000	RoHS & Green	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	H4	Samples
SN74AUP2G04YFPR	ACTIVE	DSBGA	YFP	6	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	HCN	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and



PACKAGE OPTION ADDENDUM

10-Dec-2020

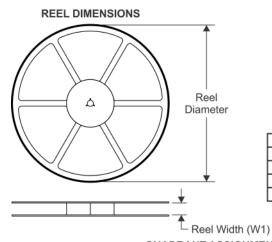
continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

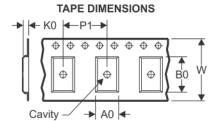
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





		Dimension designed to accommodate the component width
ı		Dimension designed to accommodate the component length
ı		Dimension designed to accommodate the component thickness
ı	W	Overall width of the carrier tape
1	P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

All diffiensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUP2G04DCKR	SC70	DCK	6	3000	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74AUP2G04DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74AUP2G04DRYR	SON	DRY	6	5000	180.0	9.5	1.15	1.6	0.75	4.0	8.0	Q1
SN74AUP2G04DSFR	SON	DSF	6	5000	180.0	9.5	1.16	1.16	0.5	4.0	8.0	Q2
SN74AUP2G04YFPR	DSBGA	YFP	6	3000	178.0	9.2	0.89	1.29	0.62	4.0	8.0	Q1

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*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AUP2G04DCKR	SC70	DCK	6	3000	180.0	180.0	18.0
SN74AUP2G04DCKR	SC70	DCK	6	3000	180.0	180.0	18.0
SN74AUP2G04DRYR	SON	DRY	6	5000	184.0	184.0	19.0
SN74AUP2G04DSFR	SON	DSF	6	5000	184.0	184.0	19.0
SN74AUP2G04YFPR	DSBGA	YFP	6	3000	220.0	220.0	35.0

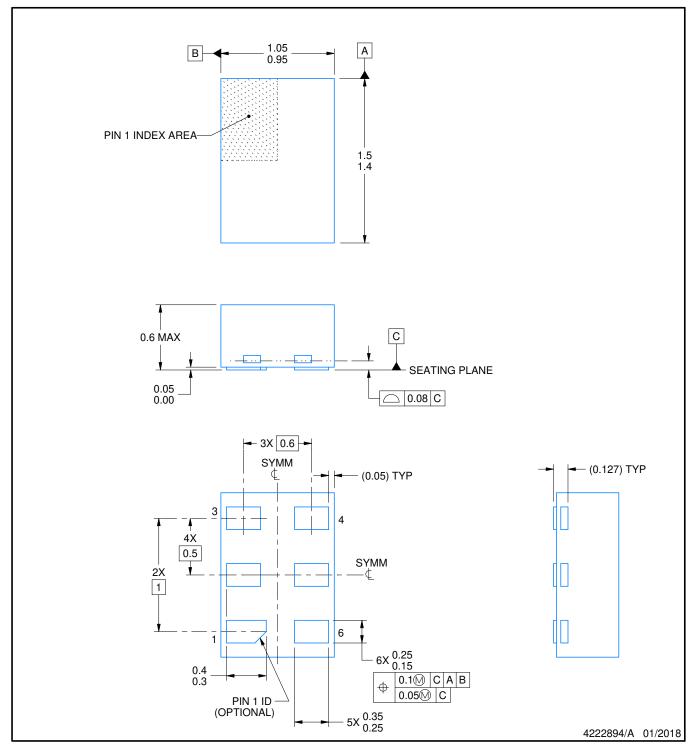


Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4207181/G





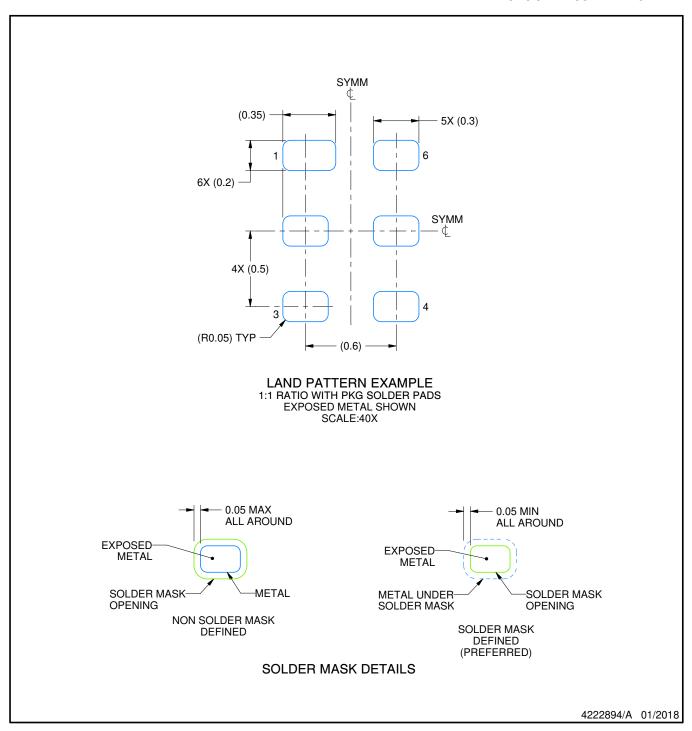


NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

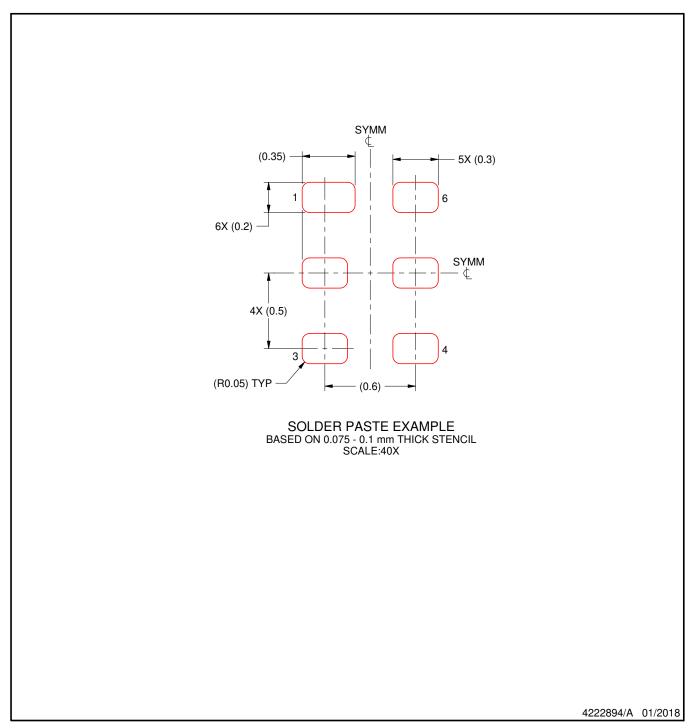




NOTES: (continued)

3. For more information, see QFN/SON PCB application report in literature No. SLUA271 (www.ti.com/lit/slua271).



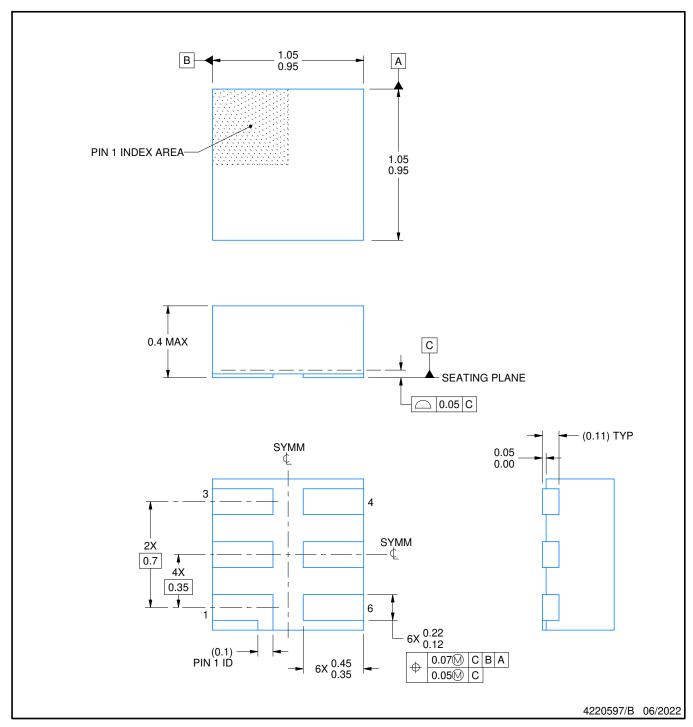


NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.







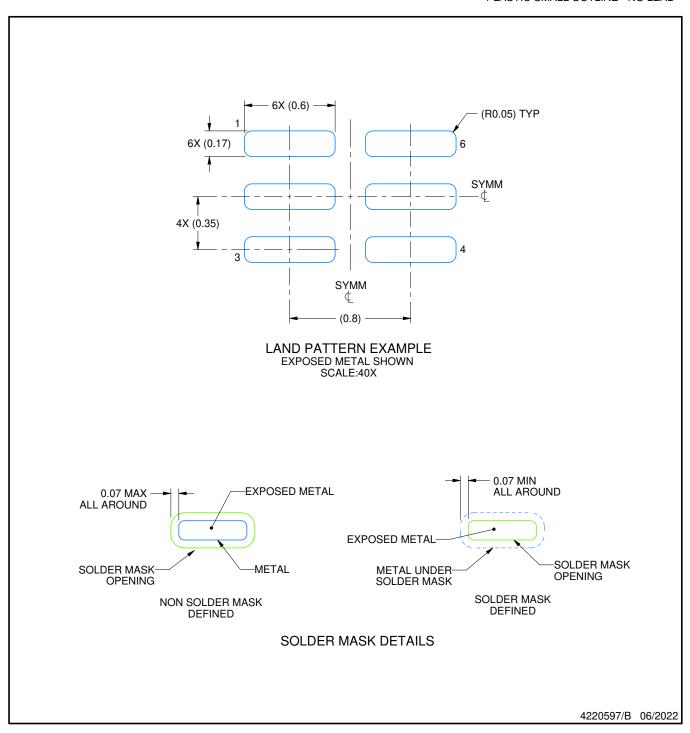
NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. Reference JEDEC registration MO-287, variation X2AAF.

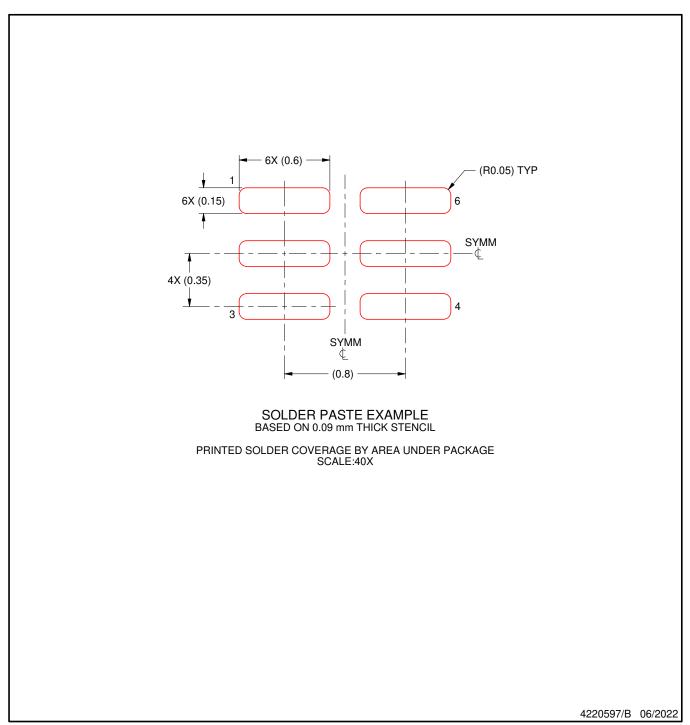




NOTES: (continued)

4. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).



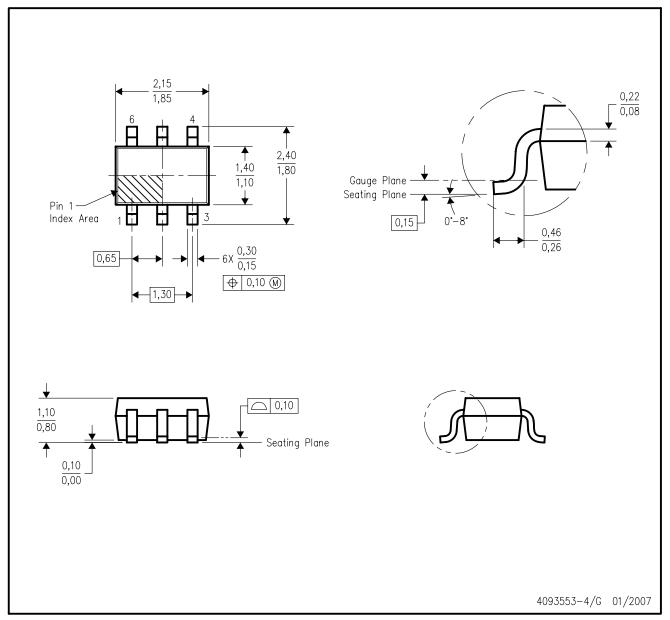


4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



DCK (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



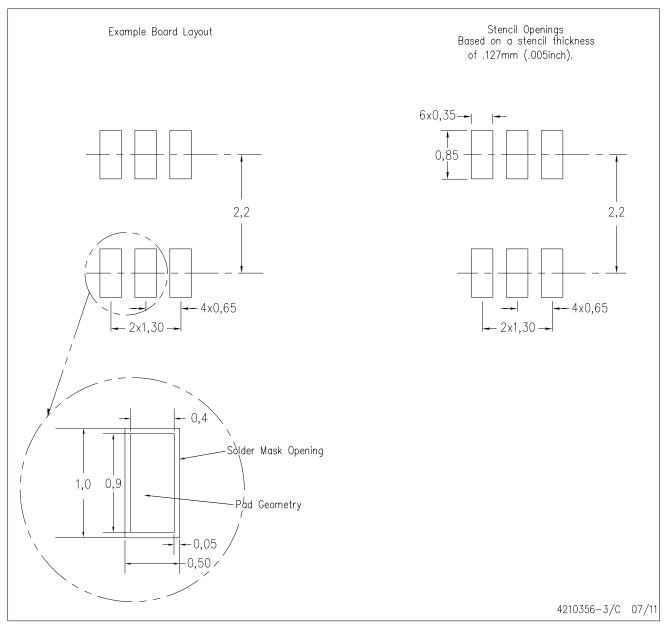
NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-203 variation AB.



DCK (R-PDSO-G6)

PLASTIC SMALL OUTLINE



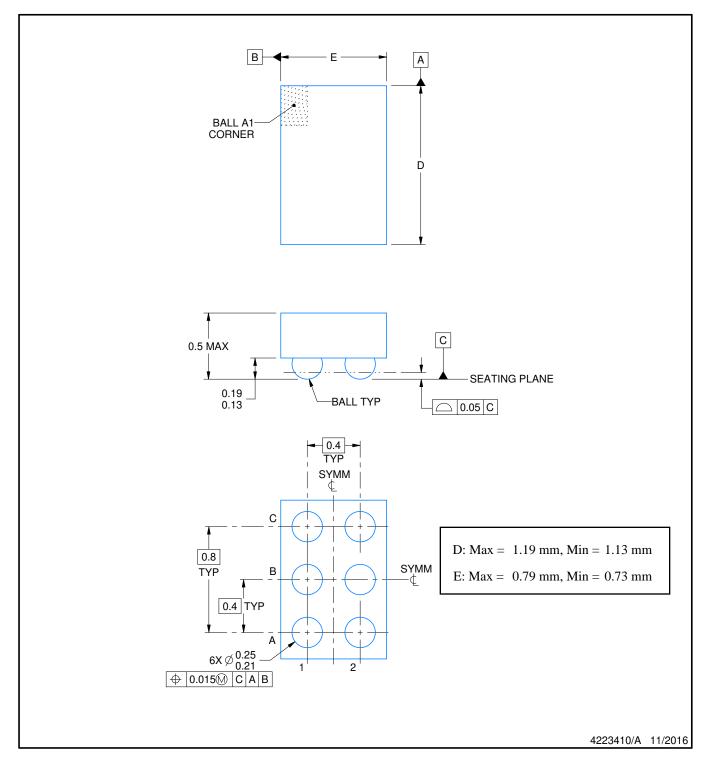
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.





DIE SIZE BALL GRID ARRAY

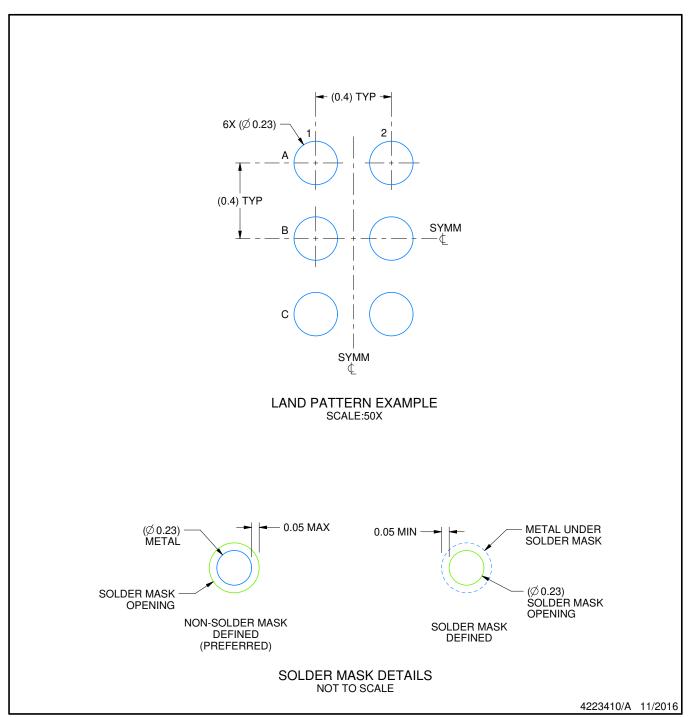


NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.



DIE SIZE BALL GRID ARRAY

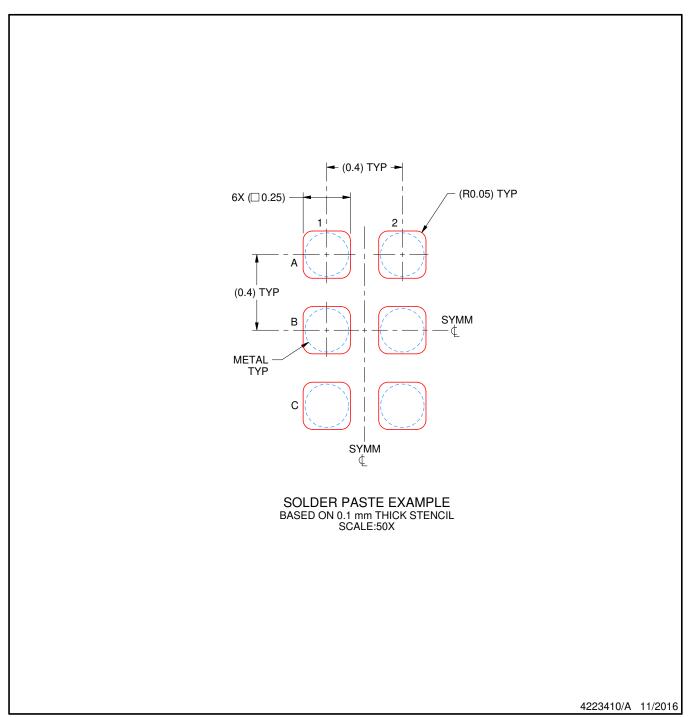


NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).



DIE SIZE BALL GRID ARRAY



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



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